

NTE7445 Integrated Circuit TTL, BCD-toDecimal Decoder/Driver 16-Lead DIP Type Package

Features:

- Full Decoding of Input Logic
- 80mA Sink-Current Capability
- All Outputs are off for Invalid BCD Input Conditions

Description:

The NTE7445 is a monolithic BCD-to-decimal decoder/driver in a 16-Lead DIP type package consisting of eight inverters and ten four-input NAND gates. The inverters are connected in pairs to make BCD input data available for decoding by the NAND gates. Full decoding of valid BCD input logic ensures that all outputs remain off for all invalid binary input conditions. This decoder features TTL inputs and high-performance, NPN output transistors designed for use as an indicator/relay driver or as an open-collector logic-circuit driver. Each of the high-breakdown output transistors (30 volts) will sink up to 80 milliamperes of current. Each input is one normalized Series 74 load. Inputs and outputs are entirely compatible for use with TTL or DTL logic circuits, and the outputs are compatible for interfacing with most MOS integrated circuits. Power dissipation is typically 215 milliwatts.

Absolute Maximum Ratings: $(T_A = 0 \text{ to } +70^{\circ}\text{C} \text{ unless otherwise specified})$

Supply Voltage (Note 1), V _{CC}	7V
Input Voltage, V _I	5.5V
Maximum Current Into Any Output (Off-State)	1mA
Operating Ambient Temperature Range	0°C to +70°C
Storage Temperature Range –	65°C to +150°C

Note 1. Voltage values are with respect to network GND terminal.

Recommended Operating Conditions:

Parameter	Symbol	Min	Тур	Max	Unit
Supply Voltage	V _{CC}	4.75	5.0	5.25	V
Off-State Output Voltage		-	Ι	30	V
Operating Ambient Temperature	Τ _Α	0	Ι	70	°C

<u>Electrical Characteristics</u>: ($T_A = 0$ to +70°C, Note 2 unless otherwise specified)

Parameter	Symbol	Test Condi	Min	Тур	Max	Unit	
High-Level Input Voltage	V _{IH}		2		-	V	
Low Level Input Voltage	V _{IL}		-	-	0.8	V	
Input Clamp Voltage	V _{IK}	$V_{CC} = Min, I_I = -12m$		Ι	-1.5	V	
On-State Output Voltage			$I_{O(on)} = 80 \text{mA}$	-	0.5	0.9	V
		V _{IL} = 800mV	$I_{O(on)} = 20mA$	-	-	0.4	V
Off-State Output Current	I _{O(off)}		-	_	250	μA	
Input Current at Max. Input Voltage	l _l	V _{CC} = Max, V _I = 5.5V	-	-	1	mA	
High–Level Input Current	Ι _{ΙΗ}	$V_{CC} = Max, V_I = 2.4V$	-	-	40	μA	
Low-Level Input Current	۱ _{IL}	$V_{CC} = Max, V_I = 0.4V$	_	_	-1.6	mA	
Supply Current	I _{CC}	V _{CC} = Max, Note 3	—	43	70	mA	

Note 2. All typical values are at $V_{CC} = 5V$, $T_A = +25^{\circ}C$. For conditions shown as Min or Max, use the appropriate value specified under recommended operating conditions for the application type.

Note 3. I_{CC} is measured with all inputs grounded and outputs open.

<u>Switching Characteristics</u>: (V_{CC} = 5V, T_A = +25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Propagation Delay Time, Low-to-High Level Output	t _{PLH}	C _L = 15pF,	-	-	50	ns
Propagation Delay Time, High-to-Low Level Output	t _{PHL}	R _L = 100Ω	-	1	50	ns

Functional Table:

		Inputs Outputs												
No.	D	С	В	Α	0	1	2	3	4	5	6	7	8	9
0	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н
1	L	L	L	Н	н	L	Н	Н	Н	Н	Н	Н	Н	Н
2	L	L	Н	L	н	Н	L	Н	Н	Н	Н	Н	Н	Н
3	L	L	Н	Н	н	Н	Н	L	Н	Н	Н	Н	Н	Н
4	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	Н	Н
5	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Н	Н
6	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Н
7	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Н	Н
8	н	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	L	Н
9	Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
	Н	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
	н	Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
INVALID	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
	н	Н	Н	L	н	Н	Н	Н	Н	Н	Н	Н	Н	Н
	н	Н	Н	Н	н	Н	Н	Н	Н	Н	Н	Н	Н	Н

H = High Level (Off), L = Low Level (On)

